L Number	Hits	Search Text	DB	Time stamp
1	33846	mram or (magnetic near2 memory)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:30
2	1784040	cell or array	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:30
3	63511	wordline or "word line"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:30
4	71427	bitline or "bit line"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:31
5	81877	first near2 cell	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:31
6	59290	second near2 cell	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:31
7	839	(first near2 cell) with (second near2 cell) with node	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:32
8	1370522	read or write	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:32
9	9513	(mram or (magnetic near2 memory)) and (cell or array) and (read or write)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:33
10	1662	((mram or (magnetic near2 memory)) and (cell or array) and (read or write)) and (wordline or "word line") and (bitline or "bit line")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:33
11	773	(((mram or (magnetic near2 memory)) and (cell or array) and (read or write)) and (wordline or "word line") and (bitline or "bit line")) and (first near2 cell)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:33
12	562	((((mram or (magnetic near2 memory)) and (cell or array) and (read or write)) and (wordline or "word line") and (bitline or "bit line")) and (first near2 cell)) and (second near2 cell)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:33
13	14	(((((mram or (magnetic near2 memory)) and (cell or array) and (read or write)) and (wordline or "word line") and (bitline or "bit line")) and (first near2 cell)) and (second near2 cell)) and ((first near2 cell) with (second near2 cell) with node)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:33

#	Count	Query	Databases	Date/Time
14	196	(((((mram or (magnetic near2 memory)) and (cell or array) and (read or write)) and (wordline or "word line") and (bitline or "bit line")) and (first near2 cell)) and (second near2 cell)) and 365/158.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:33
15.	155	(((((mram or (magnetic near2 memory)) and (cell or array) and (read or write)) and (wordline or "word line") and (bitline or "bit line")) and (first near2 cell)) and (second near2 cell)) and 365/171.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:33
16	107	(((((mram or (magnetic near2 memory)) and (cell or array) and (read or write)) and (wordline or "word line") and (bitline or "bit line")) and (first near2 cell)) and (second near2 cell)) and 365/173.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:34
17	5	((((((mram or (magnetic near2 memory)) and (cell or array) and (read or write)) and (wordline or "word line") and (bitline or "bit line")) and (first near2 cell)) and (second near2 cell)) and ((first near2 cell) with (second near2 cell) with node)) and ((((((mram or (magnetic near2 memory)) and (cell or array) and (read or write)) and (wordline or "word line") and (bitline or "bit line")) and (first near2 cell)) and (second near2 cell)) and 365/158.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:34
18	5	((((((mram or (magnetic near2 memory)) and (cell or array) and (read or write)) and (wordline or "word line") and (bitline or "bit line")) and (first near2 cell)) and (second near2 cell)) and ((first near2 cell) with (second near2 cell) with node)) and ((((((mram or (magnetic near2 memory)) and (cell or array) and (read or write)) and (wordline or "word line") and (bitline or "bit line")) and (first near2 cell)) and (second near2 cell)) and 365/171.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:34
19	0	((((((mram or (magnetic near2 memory)) and (cell or array) and (read or write)) and (wordline or "word line") and (bitline or "bit line")) and (first near2 cell)) and (second near2 cell)) and ((first near2 cell) with (second near2 cell) with node)) and ((((((mram or (magnetic near2 memory)) and (cell or array) and (read or write)) and (wordline or "word line") and (bitline or "bit line")) and (first near2 cell)) and (second near2 cell)) and 365/173.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 09:34